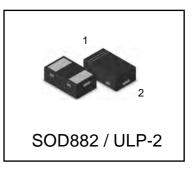


### Transient Voltage Suppressors for ESD Protection General Description

## Discription

The FTV05UAUL2 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.





#### Applications

- Cellular phones audio
- MP3 players
- Digital cameras
- Portable applicationss
- Mobile telephone

#### Features

- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- These are Pb–Free Devices
- We declare that the material of product compliance with RoHS requirements.

## Absolute Ratings (T<sub>amb</sub>=25°C )

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air discharge Contact discharge		± 15 ± 8	kV kV
ESD Voltage Per Human Body Model		16	kV
Total Power Dissipation on FR-5 Board (Note 1)	PD	200	mW
@ T <sub>A</sub> =25			
Junction and Storage Temperature Range	TJ,TSTG	-55 to150	Ĵ
Lead Solder Temperature – Maximum (10	TL	260	Ĵ
Second Duration)			

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0\*0.75\*0.62 in.

#### **Ordering information**

Device	Marking	Shipping
FTV05UAUL2	GA	10000/Tape&Reel

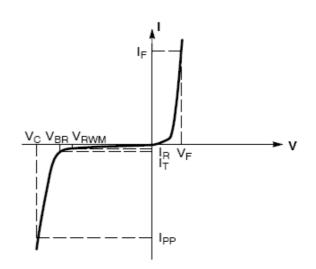


# FTV05UAUL2

## **ELECTRICAL CHARACTERISTICS**

(TA = 25 C unless otherwise noted)

Symbol	Parameter	
IPP	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
VRWM	Working Peak Reverse Voltage	
I <sub>R</sub>	Maximum Reverse Leakage Current @ VRWM	
Vbr	Breakdown Voltage @ IT	
Ι <sub>Τ</sub>	Test Current	
Ppk	Peak Power Dissipation	
С	Capacitance @ VR = 0 and f = 1.0 MHz	



Uni-Directional TVS

Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (uA) @	V <sub>BR</sub> (V) @ I <sub>T</sub>	Ι <sub>τ</sub> (mA)	I <sub>PP</sub> (A)	V <sub>C</sub> (V) @ Max I <sub>PP</sub>	Ρ <sub>ΡΚ</sub> (W) (8*20 μs)	C (pF)
		$V_{RWM}$	(Note 2)		(Note 3)	(Note 3)		
	Max	Max	Min		Max	Max	Тур	Тур
FTV05UAUL2	5.0	1.0	6.2	1.0	6	11	66	30

2. VBR is measured with a pulse test current IT at anambient temperature of 25  $^\circ\!\!C$ 

3. Surge current waveform per Figure 3.



## FTV05UAUL2

## **TYPICAL CHARACTERISTICS**

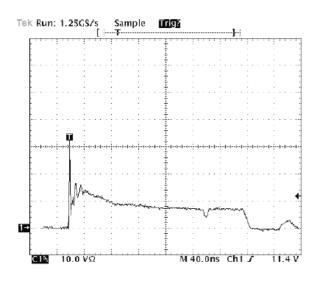
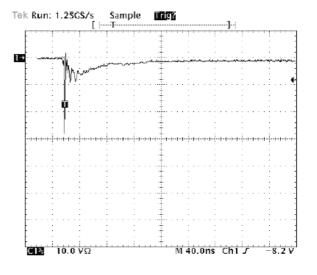


Figure 1. Positive 8kV contact per IEC 61000-4-2-LESD11D5.0T5G



# Fig 2. Negative 8kV contact per IEC 61000-4-2-LESD11D5.0T5G

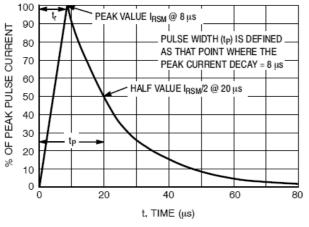


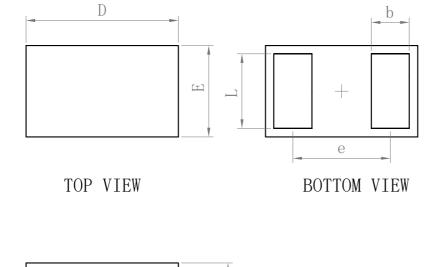
Figure 3. 8\*20 µs Pulse Waveform

First Silicon

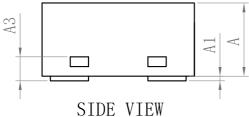


# SOD882

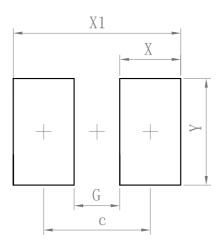
# Package Outline Dimension



SOD882				
Dim	Min	Тур	Max	
D	0.95	1.00	1.05	
Е	0.50	0.60	0.65	
е	-	0.64	-	
L	0.44	0.49	0.54	
b	0.20	0.25	0.30	
А	0.43	0.48	0.53	
A1	0	_	0.05	
A3	0.127REF.			
All Dimensions in mm				



# Suggested Pad layout



Dimensions	(mm)
С	0.70
G	0.30
Х	0.40
X1	1.10
Y	0.70

